

# EE 414 Introduction to Analog Integrated Circuits

## Take Home Exam-2

Due Date: March 25, 2015 (in class)

### Problem 1:

Due to a manufacturing error, resistor  $R_P$  has appeared in series with the base of  $Q_{REF}$  in Fig. 1. If  $I_1$  is 10% greater than its nominal value, express the value of  $R_P$  in terms of other circuit parameters. Assume  $Q_{REF}$  and  $Q_1$  are identical.

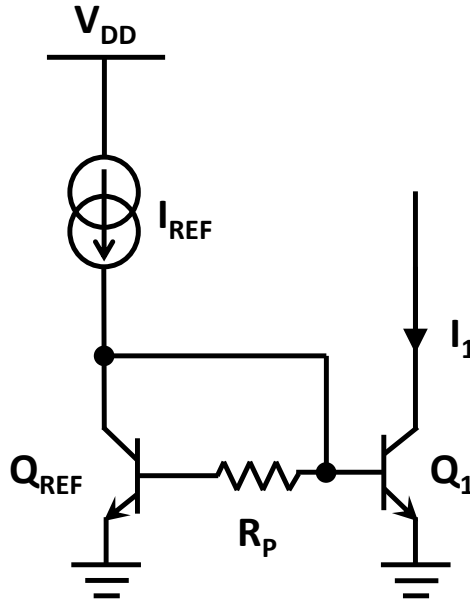


Fig. 1

### Problem 2:

Design the MOS peaking current source in Fig. 2 so that  $I_{OUT} = 0.1 \mu A$ .

(a) First, let  $I_{IN} = 1 \mu A$  and find the required value of  $R$ .

(b) Second, let  $R = 10 k\Omega$  and find the required  $I_{IN}$ .

Find the range of  $W/L$  that keeps  $M_1$  in saturation. Assume  $M_1$  and  $M_2$  are identical with  $k' = 200 \mu A/V^2$  and  $V_{th} = 0.5V$ .

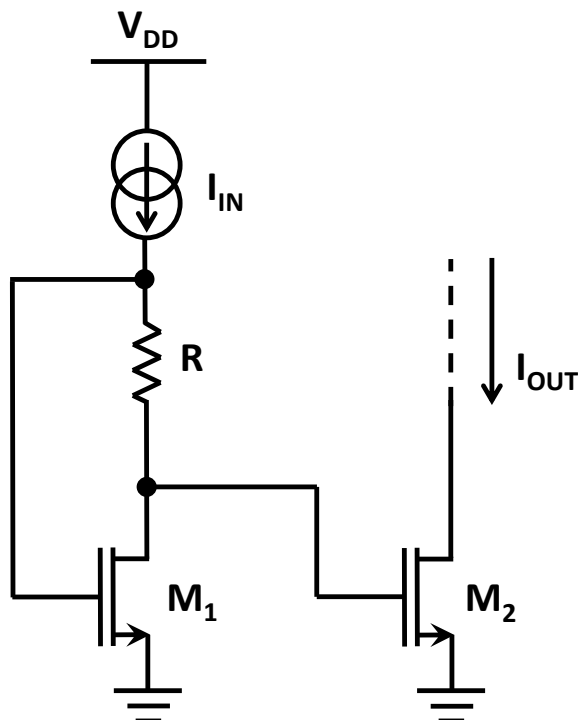


Fig. 2

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### Problem 3:

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Determine the output resistance of the current mirror in Fig. 3 as a function of transistor parameters. Neglect the body-effect. Assume that the amplifier in Fig. 3 has finite gain  $A=100$  and infinite input resistance. For small-signal analysis assume  $V_o = A(V_+ - V_-)$ . Since gain  $A$  is high, for DC analysis assume that  $V_+ = V_-$ . If the size of transistors  $M_{1,4}$  is  $W/L$ , find the size of  $M_5$  that minimizes the systematic gain error. What is the resulting gain error?

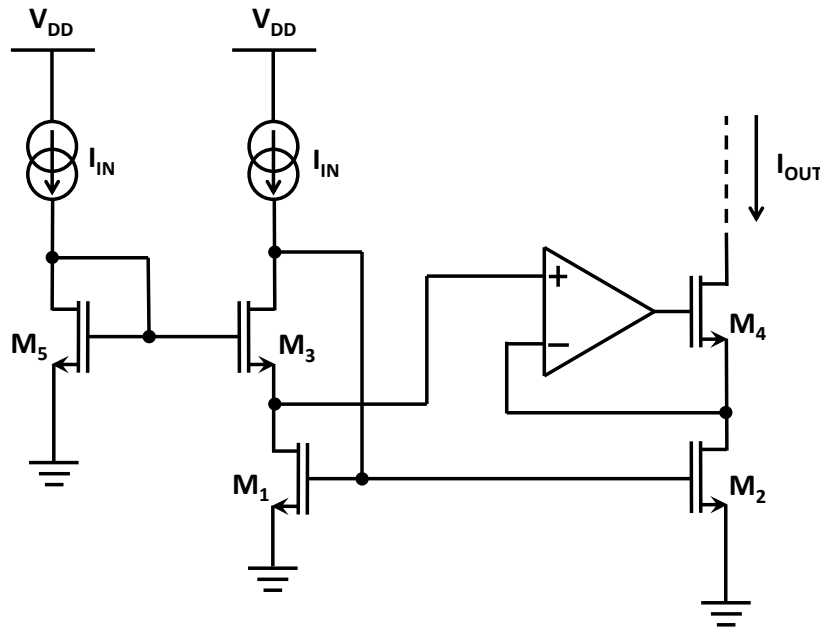


Fig. 3

### Problem 4:

Derive the equations that govern the operation of the reference in Fig. 4. (Derive the reference voltage and its temperature dependence in terms of transistor parameters)

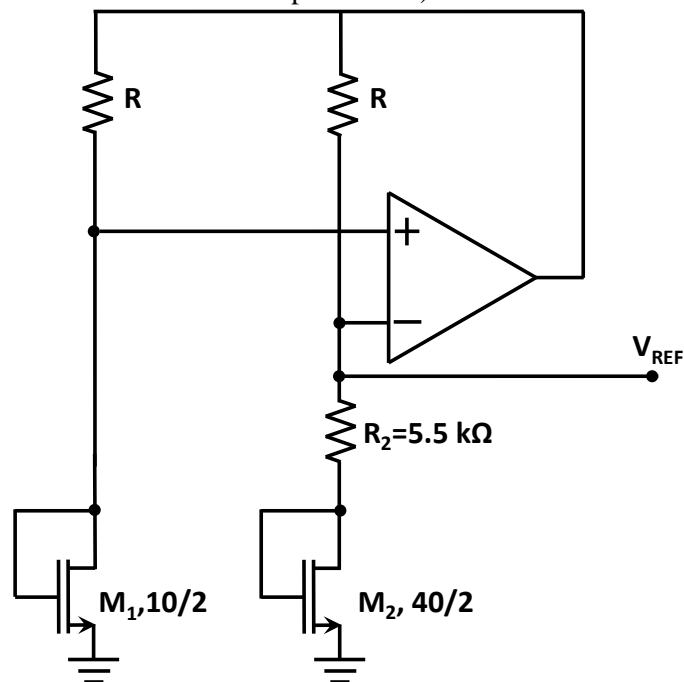


Fig. 4.